# Defect accommodation in off-stoichiometric (SrTiO<sub>3</sub>)<sub>n</sub>SrO Ruddlesden-Popper superlattices studied with positron annihilation spectroscopy ©

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### ABSTRACT

The low dielectric loss underlying the record performance of strained  $(SrTiO_3)_nSrO$  Ruddlesden–Popper films as tunable microwave dielectrics was postulated to arise from  $(SrO)_2$  faults accommodating local non-stoichiometric defects. Here, we explore the effect of non-stoichiometry on  $(SrTiO_3)_nSrO$  using positron annihilation lifetime spectroscopy on a composition series of 300 nm thick n=6  $(Sr_{1+\delta}TiO_3)_nSrO$  thin films. These films show titanium-site vacancies across the stoichiometry series, with evidence that  $TiO_x$  vacancy complexes dominate. Little change in defect populations is observed across the series, indicating the ability of Ruddlesden–Popper phases to accommodate  $\pm$  5% off-stoichiometry. This ability for defect accommodation is corroborated by scanning transmission electron microscopy with electron energy loss spectroscopy.

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Defects play a key role in understanding and engineering materials. In the  $n = \infty$  parent phase of Ruddlesden-Popper (SrTiO<sub>3</sub>)<sub>n</sub>SrO<sub>2</sub> pure SrTiO<sub>3</sub>, intrinsic point defects can dramatically affect properties: oxygen-reduced samples induce *n*-type conduction, offstoichiometric point defects decrease thermal conductivity,2ferroelectricity can emerge for ultrathin films due to nanopolarized intrinsic point defects.<sup>5</sup> The quantitative prediction, <sup>6,7</sup> identification, and measurement of these defects in SrTiO<sub>3</sub> thin films are challenging. For titanium-rich films, it is known that there is a corresponding increase in strontium vacancies, titanium antisite defects, and amorphous TiO<sub>2</sub>-rich regions.<sup>8-11</sup> For strontium-rich SrTiO<sub>3</sub>, it is well known that (SrO)<sub>2</sub> faults accommodate the strontium-excess forming disordered (SrTiO<sub>3</sub>)<sub>n</sub>SrO Ruddlesden-Popper phases. 12-14 This has been observed in thin films of off-stoichiometric  $\mbox{SrTiO}_3^{\mbox{\sc 15-18}}$  and in bulk SrTiO<sub>3</sub>, where (SrO)<sub>2</sub> faults are observed with strontium excess of >0.01 at. %. 19,20 It is yet to be explored how the (SrO)<sub>2</sub> faults

affect the vacancy populations in (SrTiO<sub>3</sub>)<sub>n</sub>SrO or strontium-rich SrTiO<sub>3</sub>. Ruddlesden–Popper superlattices have gained interest in recent years for their superconducting, <sup>21–24</sup> colossal magnetoresistive, <sup>25</sup> ferroelectric, <sup>26–30</sup> and tunable dielectric <sup>31,32</sup> properties and use as cathodes in solid fuel cells, <sup>33</sup> without full elucidation of the defect mechanisms in these materials. When epitaxially strained, these superlattice structures have the highest reported figure of merit for high-frequency tunable dielectrics, <sup>31,32</sup> at variance to the high loss seen in their titanate counterparts, SrTiO<sub>3</sub>, BaTiO<sub>3</sub>, and (Ba,Sr)TiO<sub>3</sub>, <sup>34–36</sup> Because loss at these gigahertz frequencies is caused by extrinsic defects, notably charged point defects, high figures of merit indicate their absence in these superlattices.

In SrTiO<sub>3</sub>, Ruddlesden–Popper non-stoichiometric defects are hypothesized<sup>31</sup> to be accommodated by growth (strontium excess) or reduction (titanium excess) of (SrO)<sub>2</sub> planar faults, which have a lower formation energy than that of a point defect.<sup>37</sup> Here, using positron

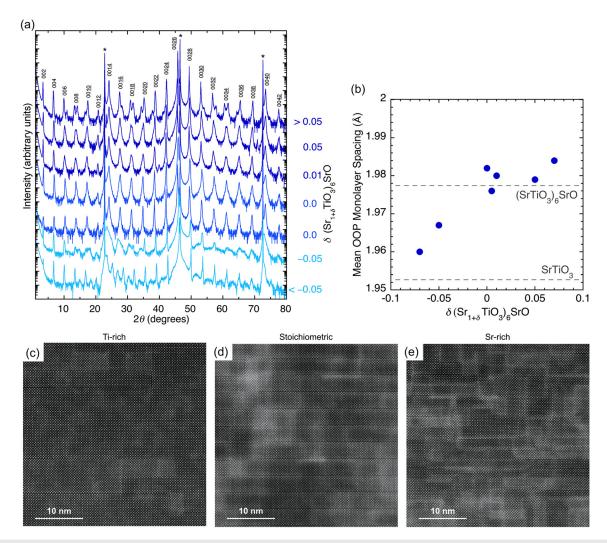
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annihilation lifetime spectroscopy (PALS), we examine how Ruddlesden–Popper structures accommodate off-stoichiometry when  $Sr_{1+\delta}TiO_3$  is inserted into an n=6 ( $SrTiO_3$ ) $_n$ SrO structure grown by oxide molecular-beam epitaxy (MBE). We have used PALS previously to examine pulsed-laser deposited (PLD) 200 nm thick titanium-rich  $SrTiO_3$  films and found a clear trend in the presence of both strontium and titanium vacancies.  $^{9,10}$  In titanium-rich  $SrTiO_3$  thin films grown homoepitaxially by PLD on (001)  $SrTiO_3$  substrates, strontium vacancies were found to dominate, crossing over to a higher proportion of titanium vacancies as the films became more stoichiometric. All films had vacancy concentrations >50 ppm.

300 nm thick n=6 (Sr<sub>1+ $\delta$ </sub>TiO<sub>3</sub>)<sub>n</sub>SrO films with a range of compositions ( $\delta=\pm$  5%) were grown on (001) SrTiO<sub>3</sub> single crystal substrates. Films were deposited using a Veeco GEN10 MBE chamber

at 900 °C (as measured by the substrate thermocouple, which is not in direct contact with the substrate; the true substrate temperature is around 800 °C) at an oxidant background pressure of  $1\times 10^{-6} \, {\rm Torr}$   $O_2 + \sim \! 10\% \, {\rm O_3}.$  Atomic layering was achieved by elemental source shuttering and calibration of individual SrO and TiO2 monolayer shutter times using reflection high-energy electron diffraction (RHEED) intensity oscillations.  $^{38-40}$  The strontium shutter time was then increased or decreased by the desired off-stoichiometry percentage for the strontium layers within the SrTiO3 portion of  $({\rm Sr}_{1+\delta}{\rm TiO}_3)_n{\rm SrO}$  to achieve the  $\delta \pm 5\% \, {\rm Sr/Ti}$  ratio.

Samples were characterized by x-ray diffraction as seen in Fig. 1(a). As the films become further off-stoichiometric, the diffraction peaks begin to split, indicating a loss in superlattice periodicity. This occurs more rapidly for titanium-rich films than strontium-rich



**FIG. 1.** (a) X-ray diffraction of  $\delta=\pm$  5% of 300 nm thick n=6 (Sr<sub>1+ $\delta$ </sub>TiO<sub>3</sub>),nSrO films grown on (001) SrTiO<sub>3</sub>. The diffraction-peak periodicity degrades with the increasing off-composition. The (001) SrTiO<sub>3</sub> substrate peaks are labeled with an asterisk (\*). (b) The mean out-of-plane (OOP) monolayer spacing of n=6 (Sr<sub>1+ $\delta$ </sub>TiO<sub>3</sub>),nSrO films calculated from the  $00\underline{26}$  peak. The y-axis error is the size of the plot markers. (c)–(e) Representative atomic-resolution MAADF-STEM images of three (Sr<sub>1+ $\delta$ </sub>TiO<sub>3</sub>),nSrO films show how off-stoichiometry is accommodated structurally through the (c) removal (titanium-rich with  $\delta \sim -0.05$ ) or (e) addition (strontium-rich with  $\delta \sim +0.05$ ) of SrO planes as compared to (d) a stoichiometric sample.

films. All films have narrow  $\omega$  rocking curves with a full-width-athalf-maximum (FWHM) comparable to the underlying substrate < 34 arc sec (0.009°) (not shown). The low FWHM of these films attests to the defect accommodating nature of (SrTiO<sub>3</sub>)<sub>n</sub>SrO despite portions of the samples being off-stoichiometric by > 5%. The main superlattice peak, 0026, is a good measure of the average out-of-plane (OOP) spacing, i.e., the average spacing between SrO and TiO2 cation layers along the [001] direction, and is plotted in Fig. 1(b). The spacing between two SrO layers is larger than that of TiO2 and SrO layers, and so higher average monolayer spacing indicates more horizontal SrO layers in the film. The average spacing between monolayers decreases sharply in strontium-deficient (titanium-rich) films due to fewer in-plane (SrO)<sub>2</sub> faults. In the strontium-rich regime, we do not see the same average monolayer spacing increase, likely because the additional (SrO)<sub>2</sub> faults that form are primarily oriented vertically (parallel to the direction of film growth).

Detailed investigation into the structure of these films was conducted using atomic-resolution scanning transmission electron microscopy (STEM). Cross-sectional samples of the titanium-rich  $(\delta \sim -0.05)$ , stoichiometric, and strontium-rich  $(\delta \sim +0.05)$  films seen in Figs. 1(c)-1(e) were prepared to thicknesses of  $\sim 20$  nm using the standard focused ion beam (FIB) lift-out method on a Thermo Scientific Helios G4 UX FIB. The samples were imaged on an aberration-corrected FEI Titan Themis at 120 kV with a probe convergence semi-angle of 21.4 mrad. Inner and outer collection angles of 36 and 107 mrad were used to collect medium-angle annular dark field (MAADF)-STEM images, respectively, revealing the atomic structure of the films, shown in Figs. 1(c)-1(e). In addition to the high-angle Z-contrast that distinguishes between heavy and light nuclei, the lower collection angles included in MAADF-STEM also contribute some diffraction contrast in the resulting images. Signatures of local crystallographic strain fields can be observed where brightening of the background highlights planar defects in the lattice.

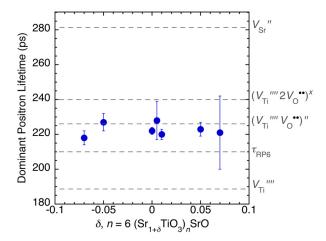
Electron energy loss spectroscopy (EELS) mapping was also performed using the same Titan system equipped with a 965 GIF Quantum ER and Gatan K2 Summit detector operated in electron counting mode, with a beam current of  $\sim$ 30 pA and scan times of 2.5–5 ms per 0.4 Å pixel.

To identify vacancies in the n = 6  $(Sr_{1+\delta}TiO_3)_nSrO$  thin-film stoichiometry series, we measured vacancy populations using variableenergy positron annihilation lifetime spectroscopy (VE-PALS). Positrons implanted in the films rapidly thermalize and then annihilate with a bulk lattice or defect state, with a characteristic lifetime  $\tau_i$ and probability  $I_i$ . The positron annihilation event emits two simultaneous  $\gamma$ -rays, one of which is detected. The time intervals with respect to the arrival of the positrons form the lifetime spectrum. By analyzing the lifetime spectrum, the positron lifetime components, characteristic of the bulk (perfect lattice) or defect states, are extracted. The positron trapping probability of a defect depends on its charge and open volume size; more negatively charged vacancy defects, such as strontium and titanium vacancies, trap more strongly. VE-PALS measurements were performed on the  $n = 6 (Sr_{1+\delta}TiO_3)_n SrO$  films using the neutron induced positron beamline (NEPOMUC) operated by FRM II at Heinz Maier-Leibnitz Zentrum (MLZ), Garching. 41,42 The positron lifetime spectra were measured using position implantation energies of 5 or 6 keV, giving a calculated mean implantation depth of 100-140 nm in SrTiO<sub>3</sub>. 9,10 The spectrometer was set to have a 40 ns

time window, and each spectrum contained  $4 \times 10^6$  counts. From a four-term free fit of the resulting spectra, the dominant state is shown for each film in Fig. 2 compared to the characteristic lifetime of possible SrTiO<sub>3</sub> vacancy states. Characteristic lifetime calculations have not been performed for the n=6 (SrTiO<sub>3</sub>) $_n$ SrO system, and so the values for vacancies in SrTiO<sub>3</sub> are used from Refs. 9 and 43 or calculated from defect structures in SrTiO<sub>3</sub> reported in Ref. 6 (also see the supplementary material) using the MIKA/DOPPLER package for density functional theory. For this work, the positron lifetime in bulk n=6 (SrTiO<sub>3</sub>) $_n$ SrO was calculated for a geometrically relaxed structure. The strontium, titanium, and titanium-oxygen vacancies are geometrically symmetric in the SrTiO<sub>3</sub> unit cell. For the titanium-dioxygen vacancy, only a linear O-Ti-O vacancy defect was considered.

If (SrO)<sub>2</sub> Ruddlesden-Popper faults do not accommodate offstoichiometry, we would expect the titanium rich-films,  $\delta < 0$ , to have higher strontium vacancy concentrations, which would produce a high dominant positron lifetime in the range of 280-290 ps as shown in Refs. 9 and 10. In contrast, dominant lifetimes for the n=6(Sr<sub>1+δ</sub>TiO<sub>3</sub>)<sub>n</sub>SrO films show little variance and are clustered between 218 and 230 ps (Fig. 2), around the TiO<sub>x</sub> vacancy lifetimes, contributing > 70% of the total spectra intensity (see supplementary material Table I). While it is non-trivial to distinguish the contribution of each  $(V_{Ti}^{""}2V_O^{\bullet})^x$ ,  $(V_{Ti}^{""}V_O^{\bullet})^{"}$ , and  $\tau_{RP6}$ , the bulk state of pure (SrTiO<sub>3</sub>)<sub>6</sub>SrO, it is clear that TiOx vacancies are the dominant vacancies found in  $n = 6 \text{ (Sr}_{1+\delta}\text{TiO}_3)_n\text{SrO}$ . When a four-term fit of the spectra is forced to include  $V_{Ti}''''$  or  $V_{Sr}''$  (see supplementary material Table I), a free term is still found between 198 and 266 ps, intermediate between the  $V_{Ti}^{\prime\prime\prime\prime}$ and  $V_{Sr}''$  values, indicating that the dominant lifetime component is not solely a convolution of titanium and strontium vacancies as found in our previous measurements on PLD SrTiO<sub>3</sub> films.<sup>9,10</sup>

The titanium-oxygen vacancy complexes,  ${\rm TiO}_{xo}$  identified by our PALS results, are likely charge neutral and explain the low loss properties of these tunable dielectric materials at high frequencies of applied electromagnetic fields. Positrons trap both neutral or negative defects. In contrast, the trapping rate to positively charged open-

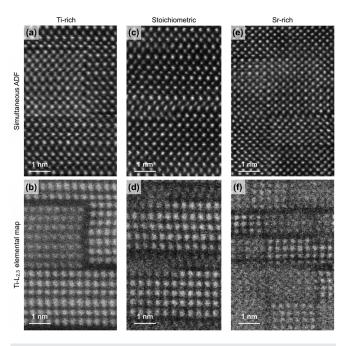


**FIG. 2.** The dominant positron lifetime from a free fit of the PALS spectra of the n=6 ( $\mathrm{Sr}_{1+\delta}\mathrm{TiO}_3$ ),  $\mathrm{nSrO}$  thin-film stoichiometry series. Dashed lines show the characteristic lifetimes associated with possible defects in  $\mathrm{SrTiO}_3$  written using Kröger–Vink notation and  $\tau_{\mathrm{RP6}}$ , the bulk lifetime for n=6 ( $\mathrm{SrTiO}_3$ ),  $\mathrm{nSrO}$ .

volume defects is negligible. Any vacancy defect is, in principle, a trap for positrons, but the Coulomb barrier presented by positively charged defects inhibits trapping. In the case of  ${\rm TiO_2}~(x=2)$  vacancies, they are charge neutral and in essence regions of  $({\rm SrO})_2$  faults, seen as  ${\rm SrTiO_3} + (V_{Ti}''''2V_O^*)'' = {\rm SrO.}^{46}$  If they exist, vacancies of  $(V_{Ti}''''V_O^*)''$ , (x=1), are also likely charge neutral with the addition of two electrons from nearby oxygen vacancies. These results establish the ability of the  $({\rm SrTiO_3})_n{\rm SrO}$  structure to mitigate defects and explain the exceptional performance of strained  $({\rm SrTiO_3})_n{\rm SrO}$  films at gigahertz frequencies where loss has been identified to be due to charged point defects.  $^{34-36}$ 

The structural accommodations revealed by STEM-EELS support this interpretation of the PALS data. Dark boundaries between SrO planes in Figs. 1(c)-1(e) and 3 can easily be traced between regions of continuous perovskite, most notably as the boundaries between the n=6 Ruddlesden-Popper layers. In general, atomic columns of strontium and titanium can be differentiated by their relative brightness, with heavy strontium atoms appearing brighter than comparatively lighter titanium sites. Areas where all atomic sites show similar contrast suggest projection through atomic columns containing both strontium and titanium, indicating regions that are crystallographically offset by  $\frac{a}{2}$  [110] due to an (SrO)<sub>2</sub> Ruddlesden-Popper fault.

In the stoichiometric case, Figs. 1(d), 3(c), and 3(d), discrete (SrO)<sub>2</sub> layers are separated by clear gaps in the titanium elemental map where SrO planes form rock salt boundaries. The nominally stoichiometric film displays general adherence to the n=6 Ruddlesden–Popper structure although some disruptions are observed as inclusions of vertical SrO planes and subtle crystalline defects like the step edge shown here.



**FIG. 3.** Atomic-resolution EELS mapping of the Ti- $L_{2,3}$  edge highlights how the stoichiometric (c) and (d) Ruddlesden–Popper structure adapts to accommodate offstoichiometry by forming (a) and (b) larger (titanium-rich with  $\delta \sim -0.05$ ) or (e) and (f) smaller (strontium-rich with  $\delta \sim +0.05$ ) blocks of continuous SrTiO<sub>3</sub> between SrO plane boundaries.

The titanium-rich (strontium-poor) film in Figs. 1(c), 3(a), and 3(b) shows how the Ruddlesden-Popper phase has adjusted to accommodate its off-stoichiometry: larger regions of continuous SrTiO<sub>3</sub> have formed as excess titanium fills in-between neighboring SrO rock salt layers (or, equivalently, as SrO rock salt boundaries are removed). The elemental map in Fig. 3(b) clearly shows regions of both higher n (upper right corner) and projection through an  $(SrO)_2$ Ruddlesden-Popper fault along the growth direction (central region). The regions where the titanium atomic columns are clearly resolved (for example, at the upper right corner and lower half of the image) correspond to a coherent SrTiO<sub>3</sub>-type structure where the TiO<sub>2</sub> planes are continuous in the electron projection direction (i.e., in and out of the page). The regions where titanium atomic contrast is less clear (as is the case for the central part of the image) indicate projection through two or more local SrTiO<sub>3</sub> structures offset relative to each other in the plane of the page by a half unit cell, as would form at a Ruddlesden-Popper boundary or the SrO rock salt planes between layers.

In contrast to the titanium-rich film, the strontium-rich film in Figs. 1(e), 3(e), and 3(f) forms extra SrO planes beyond the normal Ruddlesden–Popper phase, breaking up the n=6 layers both horizontally and vertically into regions of locally smaller effective n, similar to effects observed in other strontium-rich SrTiO<sub>3</sub> films. The titanium map of the strontium-rich film, Fig. 3(f), provides a clear view of extra SrO planes forming both vertically and horizontally, dividing Ruddlesden–Popper layers into "bricks" of much smaller effective n. The extra SrO planes, which are directly visible in the elemental map, form normal to the plane of the page. The regions of reduced titanium atomic contrast also indicate the formation of extra SrO planes parallel to the plane of the page, resulting in mixed projection through offset SrTiO<sub>3</sub> blocks as shown in Fig. 3(b).

The defect mitigating nature of (SrTiO<sub>3</sub>)<sub>n</sub>SrO Ruddlesden–Popper phases was probed using PALS by introducing off-stoichiometric Sr<sub>1+δ</sub>TiO<sub>3</sub> into the Ruddlesden-Popper superlattice to form a series of 300 nm thick n = 6  $(Sr_{1+\delta}TiO_3)_nSrO$  thin films grown by MBE on (001) SrTiO<sub>3</sub>. Atomic-resolution STEM and EELS show how offstoichiometric films adjust structurally to accommodate either excess titanium (fewer SrO rock salt boundaries) or excess strontium (additional SrO rock salt boundaries). The lack of variance with offstoichiometry seen in corresponding PALS spectra and the absence of trapping to strontium vacancies in titanium-rich films further support this conclusion that (SrO)2 faults are indeed accommodating nonstoichiometry without dominant introduction of cation monovacancies as observed in PLD  $Sr_{1+\delta}TiO_3$  thin films. <sup>9,10</sup> The observed  $TiO_x$  vacancies are likely charge neutral nano-regions of SrO faults, SrTiO3 +  $(V_{T_i}^{""} 2V_O^{\bullet \bullet})^x$  = SrO. Further studies on the contribution of oxygen vacancies and antisite defects, which cannot be fully studied using PALS, are needed to provide full understanding of the defect mechanisms in  $(SrTiO_3)_nSrO$ .

See the supplementary material for additional details on the PALS experimental setup, the mean positron lifetime plotted for the  $n=6~(\mathrm{Sr}_{1+\delta}\mathrm{TiO}_3)_n\mathrm{SrO}$  thin film series, a table of positron lifetimes fitted from the PALS spectra for all samples, and further details of the DFT calculations of the positron characteristic lifetimes.

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### DATA AVAILABILITY

The data that support the findings of this study are available in the supplementary material and from the corresponding author upon reasonable request.

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### **Supplementary Information**

Defect accommodation in off-stoichiometric  $(SrTiO_3)_nSrO$  Ruddlesden-Popper superlattices studied with positron annihilation spectroscopy

### Positron annihilation lifetime spectroscopy experiments

Experimental variable energy positron annihilation lifetime spectroscopy (VE-PALS) measurements were performed on seven n = 6 (Sr<sub>1+ $\delta$ </sub>TiO<sub>3</sub>)<sub>n</sub>SrO films with  $\delta$  varying from -0.07 to +0.07 using the PLEPS instrument on the neutron induced positron beamline (NEPOMUC) operated by FRM II at the Heinz Maier-Leibnitz Zentrum (MLZ), Garching. Measurements were performed for positron implantation energies of 4, 5, and 6 keV. Each spectrum contained  $4\times10^6$  counts and the instrument resolution function was described by the sum of three Gaussians and had a shape parameter full-width-half-maximum varying from 203 to 276 ps over the period of the measurements. The spectra were fitting using the package PALSfit v3.195 from the Technical University of Denmark.<sup>1</sup> The detailed fits obtained for the seven 5 kV spectra are given in Table I. The mean positron lifetimes, obtained from the four lifetime free fits, are shown in FIG. S1. The mean positron lifetime is the sum of all of the lifetime components obtained, each weighted by the intensity of that component. The mean positron lifetime is in principle independent of the number of lifetime components used in the deconvolution. The dominant lifetime component shown in FIG. 2 is more characteristic of the dominant open-volume defect population contributing to the positron annihilation lifetime spectrum.

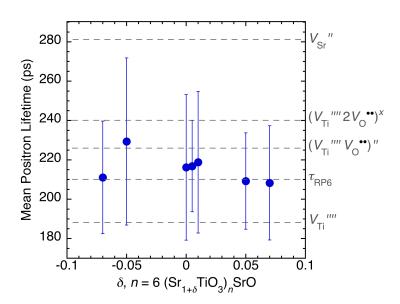


FIG S1. Mean positron lifetime values obtained for 5 keV spectra from near-stoichiometric  $n = 6 \text{ (Sr}_{1+\delta}\text{TiO}_3)_n\text{SrO}$ Ruddlesden-Popper films assuming four components using PALSfit.

**Table S1** Positron lifetime component values obtained for 5 keV spectra from near-stoichiometric n = 6 (Sr<sub>1+ $\delta$ </sub>TiO<sub>3</sub>)<sub>n</sub>SrO Ruddlesden-Popper films using PALSfit. If a fit component value is fixed this is denoted by F. Fits were performed assuming four lifetime components, but three lifetime (3L) free fits are also included for comparison.

| Sample  | Fit   | τ <sub>1</sub> (ps) | <i>I</i> <sub>1</sub> (%) | τ <sub>2</sub> (ps) | I <sub>2</sub> (%) | τ <sub>3</sub> (ps) | I <sub>3</sub> (%) | $\chi^2$ |  |  |  |  |  |
|---|---|---------------------|---------------------------|---------------------|--------------------|---------------------|--------------------|----------|--|--|--|--|--|
| Titanium rich / strontium poor, $n = 6 (Sr_{1+\delta}TiO_3)_nSrO$ |   |                     |                           |                     |                    |                     |                    |          |  |  |  |  |  |
| $\delta = -0.07$  | Free fit  | 107(11)             | 11(3)                     | 218(4)              | 88(2)              | 469(70)             | 1.5(8)             | 0.965    |  |  |  |  |  |
| NMD361  | Free fit (3L)   | 156(5)              | 36(4)                     | 239(3)              | 64(4)              | 1306(97)            | 0.15(2)            | 0.995    |  |  |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed                                       | 33(18)              | 4(1)                      | 194(2)              | 75(1)              | 281F                | 21(1)              | 1.050    |  |  |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                           | 183F                | 63(2)                     | 257(5)              | 37(2)              | 747(366)            | 0.2(2)             | 1.058    |  |  |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime} \& V_{Sr}^{\prime\prime}$ fixed  | 183F                | 63(6)                     | 236(36)             | 20(3)              | 281F                | 18(9)              | 1.064    |  |  |  |  |  |
|   |   |                     |                           |                     |                    |                     |                    |          |  |  |  |  |  |
| $\delta = -0.05$  | Free fit  | 80(16)              | 6(2)                      | 227(5)              | 87(3)              | 358(36)             | 7(4)               | 1.120    |  |  |  |  |  |
| NMD397  | Free fit (3L)   | 157(6)              | 27(3)                     | 254(3)              | 73(3)              | 1036(104)           | 0.15(4)            | 1.147    |  |  |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed                                       | 22(39)              | 5(6)                      | 202(2)              | 58(4)              | 281F                | 35(1)              | 1.132    |  |  |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                           | 183F                | 44(1)                     | 266(2)              | 56(1)              | 789(249)            | 0.2(1)             | 1.158    |  |  |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ & $V_{Sr}^{\prime\prime}$ fixed | 183F                | 40(7)                     | 237(29)             | 27(4)              | 281F                | 33(10)             | 1.144    |  |  |  |  |  |

| Stoichiometric, $n = 6 (Sr_{1+\delta}TiO_3)_nSrO$ |  |               |                         |                                    |        |           |          |       |  |  |  |
|---|--|---------------|-------------------------|------------------------------------|--------|-----------|----------|-------|--|--|--|
| $\delta = 0$                                      | Free fit   | 102(11)       | 7(2)                    | 222(2)                             | 92(1)  | 571(66)   | 0.9(3)   | 1.054 |  |  |  |
| NMD330  | Free fit (3L)  | 133(8)        | 14(2)                   | 229(2)                             | 85(2)  | 913(47)   | 0.32(4)  | 1.081 |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed  | 117(65)       | 5(8)                    | 206(9)                             | 75(5)  | 281F      | 20(3)    | 0.914 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                                | 183F          | 50(3)                   | 249(5)                             | 50(3)  | 688(436)  | 0.2(3)   | 0.913 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime\prime} \& V_{Sr}^{\prime\prime}$ fixed | 183F          | 48(7)                   | 235(21)                            | 37(3)  | 281F      | 15(9)    | 0.916 |  |  |  |
| $\delta = 0$                                      | Free fit   | 161(27)       | 22(19)                  | 228(11)                            | 77(19) | 494(80)   | 1.0(8)   | 0.991 |  |  |  |
| NMD399  | Free fit (3L)  | 204(2)        | 89(3)                   | 315(13)                            | 11(3)  | 2014(486) | 0.03(1)  | 1.023 |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed  | 91(77)        | 2(3)                    | 201(5)                             | 78(1)  | 281F      | 20(2)    | 0.987 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                                | 183F          | 50(3)                   | 245(5)                             | 50(3)  | 574(136)  | 0.5(4)   | 0.979 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime} \& V_{Sr}^{\prime\prime}$ fixed       | 183F          | 44(12)                  | 222(20)                            | 39(7)  | 281F      | 17(6)    | 0.988 |  |  |  |
| Strontium   | rich / titanium  | poor, $n = 6$ | δ (Sr <sub>1+δ</sub> Ti | iO <sub>3</sub> ) <sub>n</sub> SrO |        |           |          |       |  |  |  |
| $\delta = 0.01$                                   | Free fit   | 98(14)        | 8(2)                    | 220(3)                             | 90(2)  | 524(54)   | 1.7(5)   | 1.065 |  |  |  |
| NMD355  | Free fit (3L)  | 184(4)        | 63(5)                   | 269(6)                             | 37(5)  | 1597(86)  | 0.21(2)  | 1.120 |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed  | 193(2)        | 74(1)                   | 281F                               | 25(2)  | 905(323)  | 0.3(1)   | 1.113 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                                | 183F          | 54(3)                   | 252(5)                             | 46(2)  | 677(155)  | 642(298) | 1.093 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ & $V_{Sr}^{\prime\prime}$ fixed      | 183F          | 56(9)                   | 228(38)                            | 20(3)  | 281F      | 24(7)    | 1.120 |  |  |  |
| $\delta = 0.05$                                   | Free fit   | 141(12)       | 21(6)                   | 223(4)                             | 79(6)  | 630(81)   | 0.5(2)   | 1.000 |  |  |  |
| NMD394  | Free fit (3L)  | 170(5)        | 49(6)                   | 244(5)                             | 51(6)  | 1637(149) | 0.09(1)  | 1.026 |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed  | 54(20)        | 5(1)                    | 197(20)                            | 79(1)  | 281F      | 17(1)    | 0.970 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                                | 89(49)        | 2(2)                    | 183F                               | 59(6)  | 252(5)    | 38(4)    | 0.993 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ & $V_{Sr}^{\prime\prime}$ fixed      | 183F          | 65(4)                   | 254(32)                            | 30(22) | 281F      | 4(26)    | 0.982 |  |  |  |
| $\delta = 0.07$                                   | Free fit   | 161(32)       | 28(19)                  | 221(21)                            | 71(34) | 457(199)  | 1(2)     | 1.001 |  |  |  |
| NMD392  | Free fit (3L)  | 188(3)        | 77(6)                   | 267(9)                             | 23(6)  | 2117(178) | 0.10(1)  | 1.004 |  |  |  |
|   | $V_{Sr}^{\prime\prime}$ fixed  | 53(47)        | 2(1)                    | 194(17)                            | 83(1)  | 281F      | 15(1)    | 1.022 |  |  |  |
|   | $V_{Ti}^{\prime\prime\prime\prime}$ fixed                                | 183F          | 65(3)                   | 249(7)                             | 34(2)  | 610(471)  | 0.2(4)   | 1.022 |  |  |  |
|   | V'''' & V'''<br>fixed  | 183F          | 64(7)                   | 231(25)                            | 25(2)  | 281F      | 11(6)    | 1.024 |  |  |  |

### **Positron lifetime calculations**

The calculations were performed with the MIKA/Doppler package, where the electron density of the solid is approximated by the non-self-consistent superposition of free atom electron densities in the absence of the positron (the so-called 'conventional scheme'). This approximation to the complete two-component density functional theory (TCDFT) has been found to give positron lifetimes close to TCDFT as well as experimental values. The electron-positron enhancement factor obtained from the data of Arponen and Pajanne, 2 parameterization by Boronski and Nieminen (BN), 3 described within the local density approximation (LDA), and with an expression obtained by Barbiellini and co-workers, 4.5 (referred to as AP) described within the generalized gradient approximation (GGA) were used. Calculations were performed using a 512 atom supercell of n = 6 (Sr<sub>1</sub>TiO<sub>3</sub>)<sub>n</sub>SrO Ruddlesden-Popper phase structure, the resulting bulk positron lifetime value was 208 ps. A similar calculation for a 1080 atom supercell of SrTiO<sub>3</sub> gave a value of 151 ps, in agreement with previous work. 6 Calculations were also performed using a similar super cell size for the  $(V_{Tl}^{mil}V_0^{\bullet \bullet})^m$  divacancy defect, and for a linear  $(V_0^{\bullet \bullet}V_{Tl}^{mil}V_0^{\bullet \bullet})^m$  trivacancy complexes in SrTiO<sub>3</sub>, these yielded values of 226 ps and 240 ps, respectively. The latter value is slightly smaller than the previously reported value of 247 ps. 7 In these calculations involving titanium vacancy related defects, the geometry of the defects were not relaxed.

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